

SHINDENGEN

Schottky Barrier Diode

Twin Diode

S15SC4M

40V 15A

FEATURES

- $T_j=150^\circ\text{C}$
- P_{RRSM} avalanche guaranteed
- Small θ_{jc}
- High current capacity

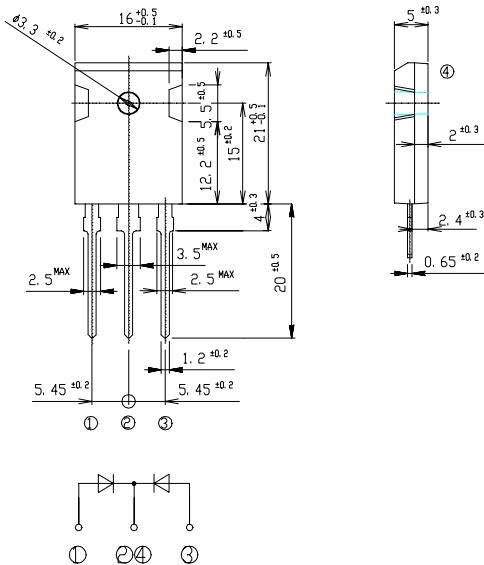
APPLICATION

- Switching power supply
- DC/DC converter
- Home Appliances, Office Equipment
- Telecommunication

OUTLINE DIMENSIONS

Case : MTO-3P

Unit : mm



RATINGS

● Absolute Maximum Ratings (If not specified $T_c=25^\circ\text{C}$)

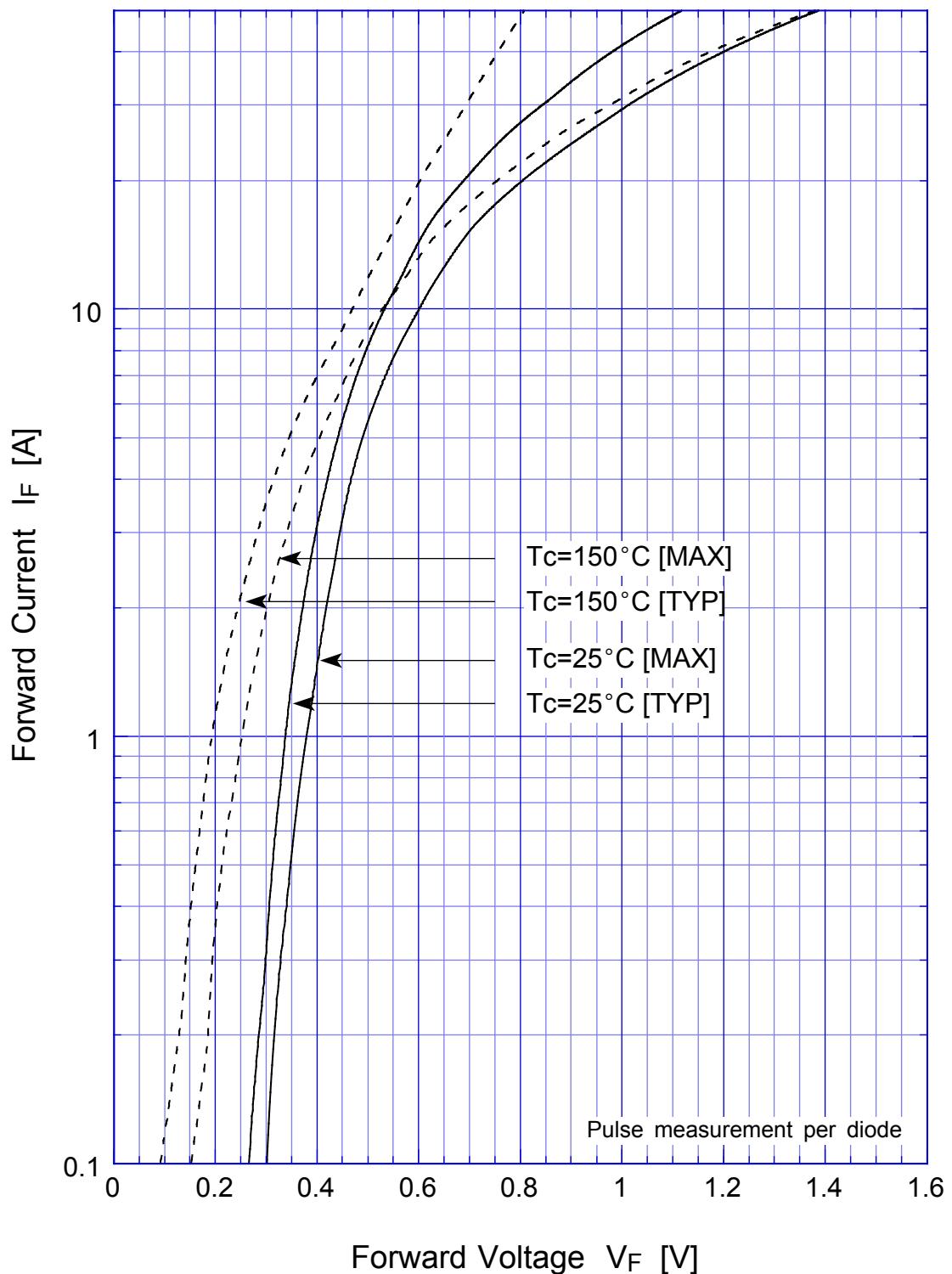
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T_{stg}		-40 ~ 150	°C
Operating Junction Temperature	T_j		150	°C
Maximum Reverse Voltage	V_{RM}		40	V
Repetitive Peak Surge Reverse Voltage	V_{RRSM}	Pulse width 0.5ms, duty 1/40	45	V
Average Rectified Forward Current	I_O	50Hz sine wave, R-load, Rating for each diode $I_O/2$, $T_c=135^\circ\text{C}$	15	A
Peak Surge Forward Current	I_{FSM}	50Hz sine wave, Non-repetitive 1 cycle peak value, Rating of per diode, $T_j=125^\circ\text{C}$	170	A
Repetitive Peak Surge Reverse Power	P_{RRSM}	Pulse width 10 μs , Rating of per diode, $T_j=25^\circ\text{C}$	330	W
Mounting Torque	T_{OR}	(Recommended torque: 0.5N·m)	0.8	N·m

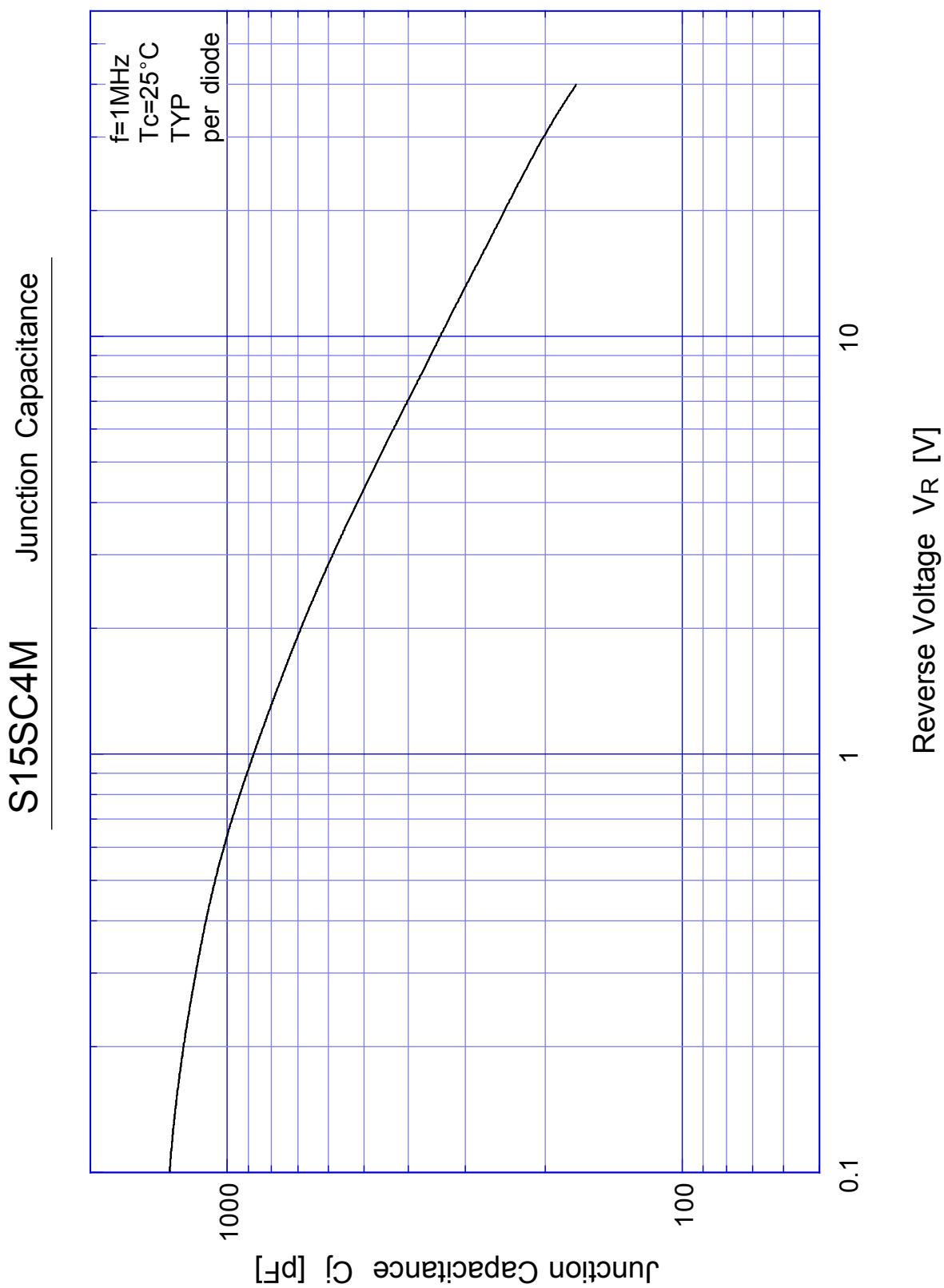
● Electrical Characteristics (If not specified $T_c=25^\circ\text{C}$)

Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	V_F	$I_F=7.5\text{A}$, Pulse measurement, Rating of per diode	Max.0.55	V
Reverse Current	I_R	$V_R=V_{RM}$, Pulse measurement, Rating of per diode	Max.5	mA
Junction Capacitance	C_j	$f=1\text{MHz}$, $V_R=10\text{V}$ Rating of per diode	Typ.340	pF
Thermal Resistance	θ_{jc}	junction to case	Max.1.2	°C/W

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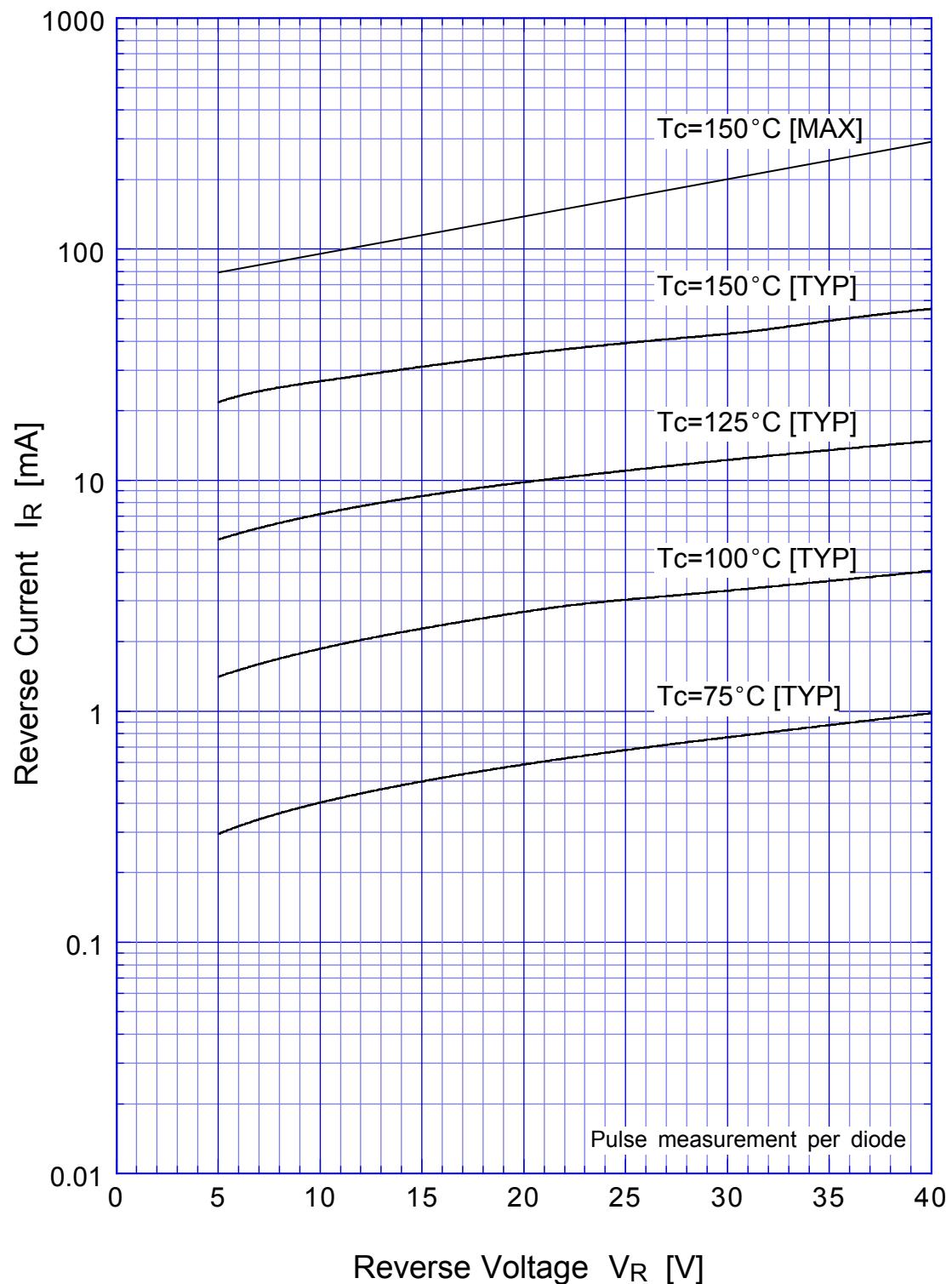
Forward Voltage





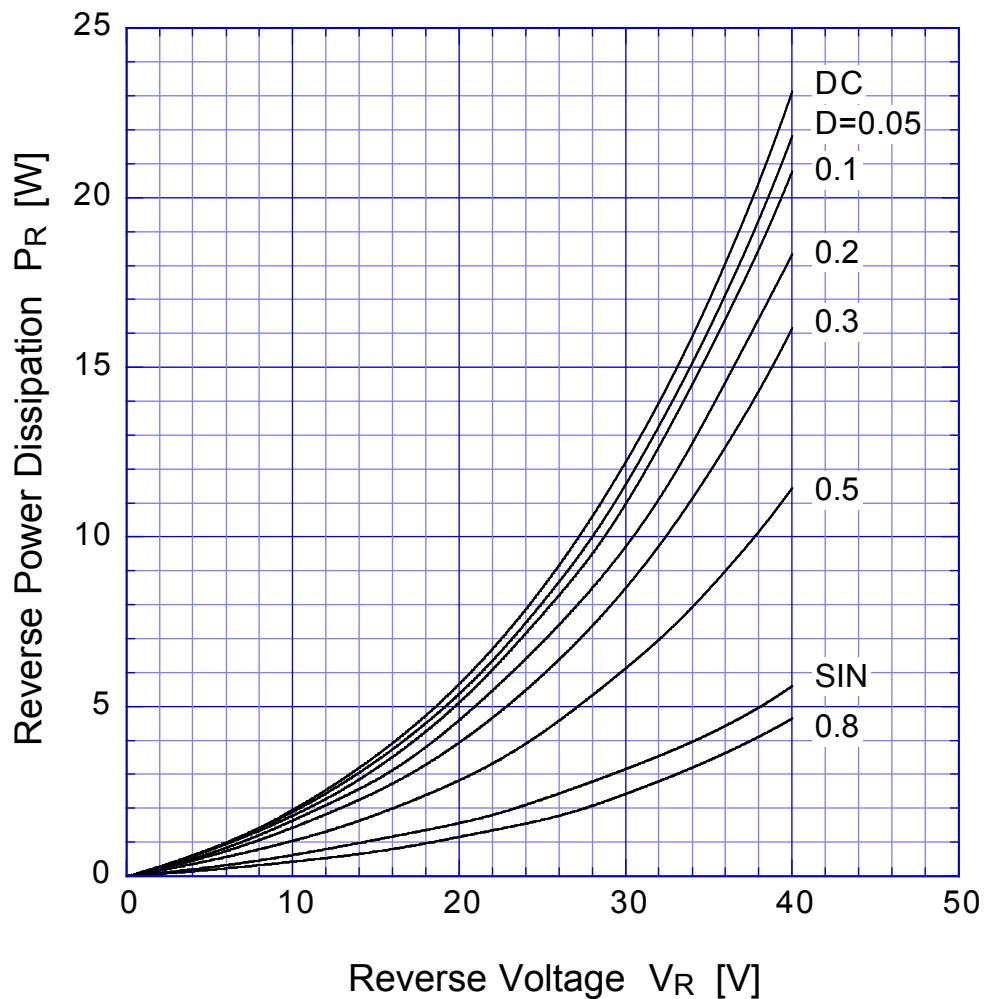
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Reverse Current

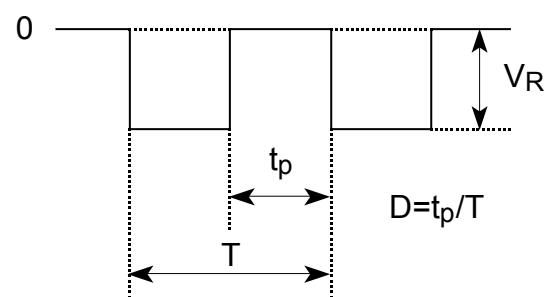


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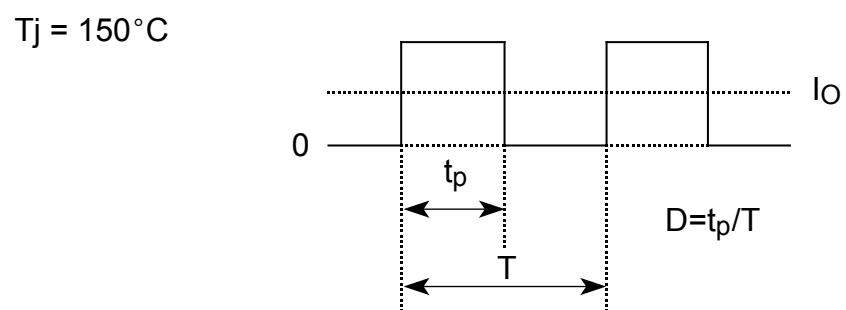
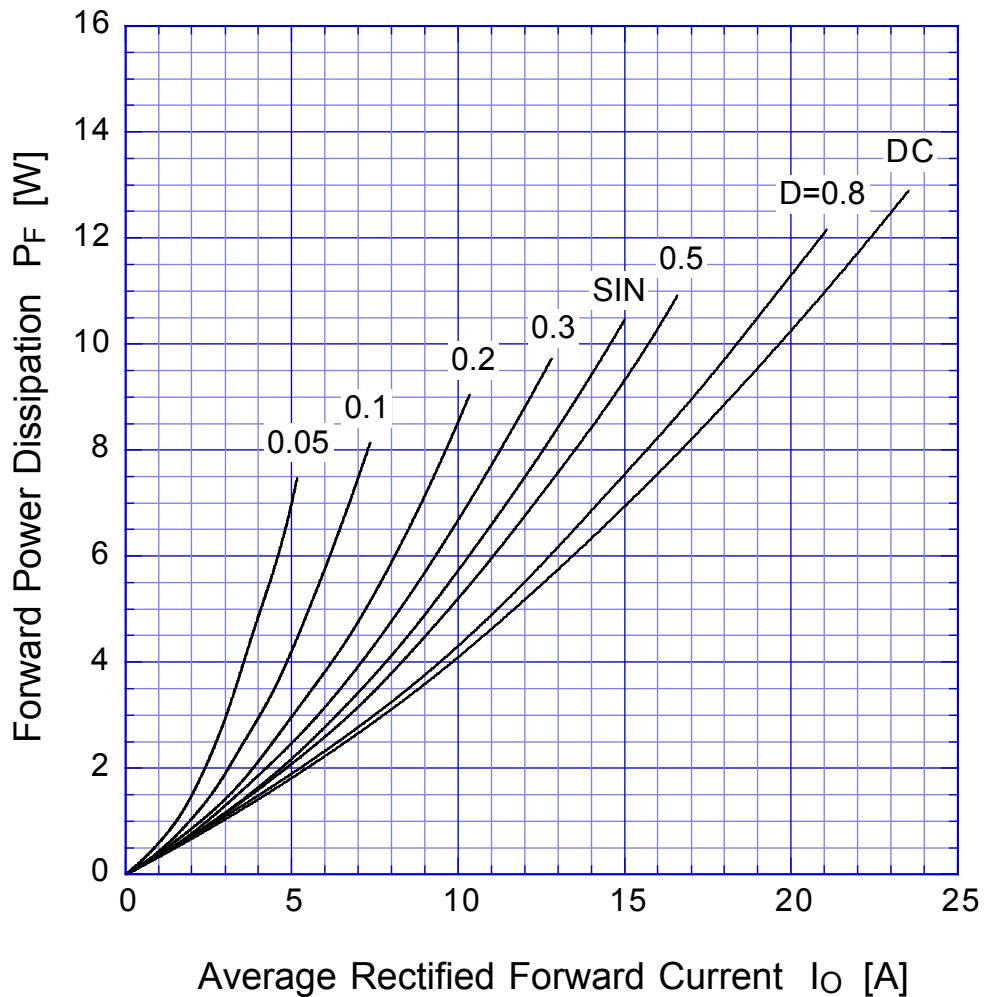
Reverse Power Dissipation

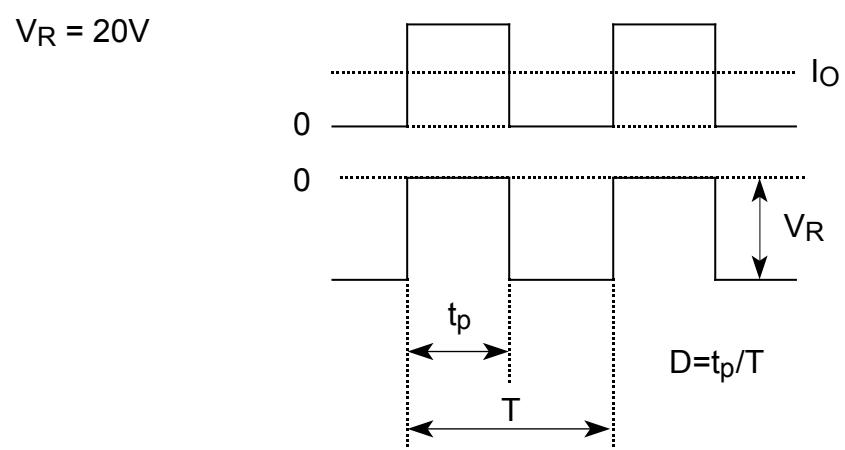
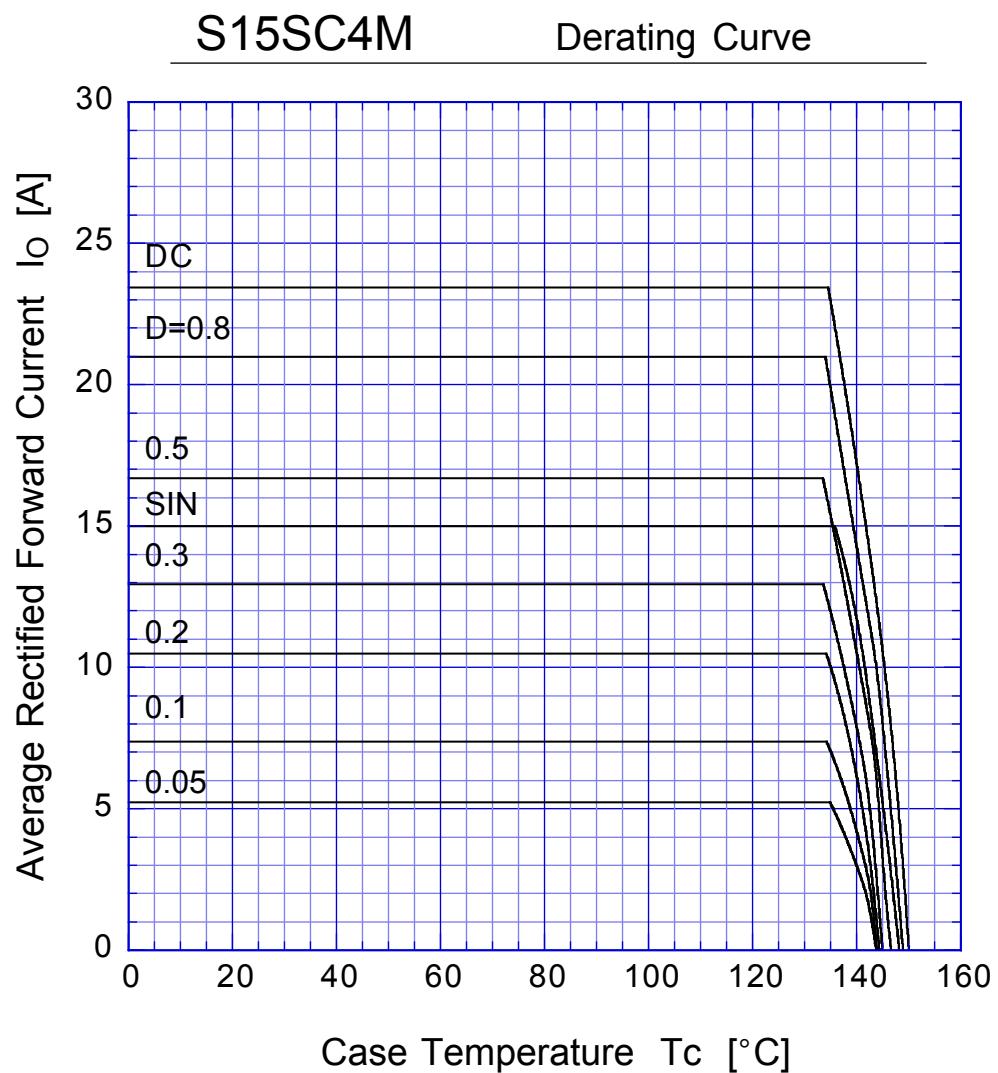


$T_j = 150^\circ\text{C}$

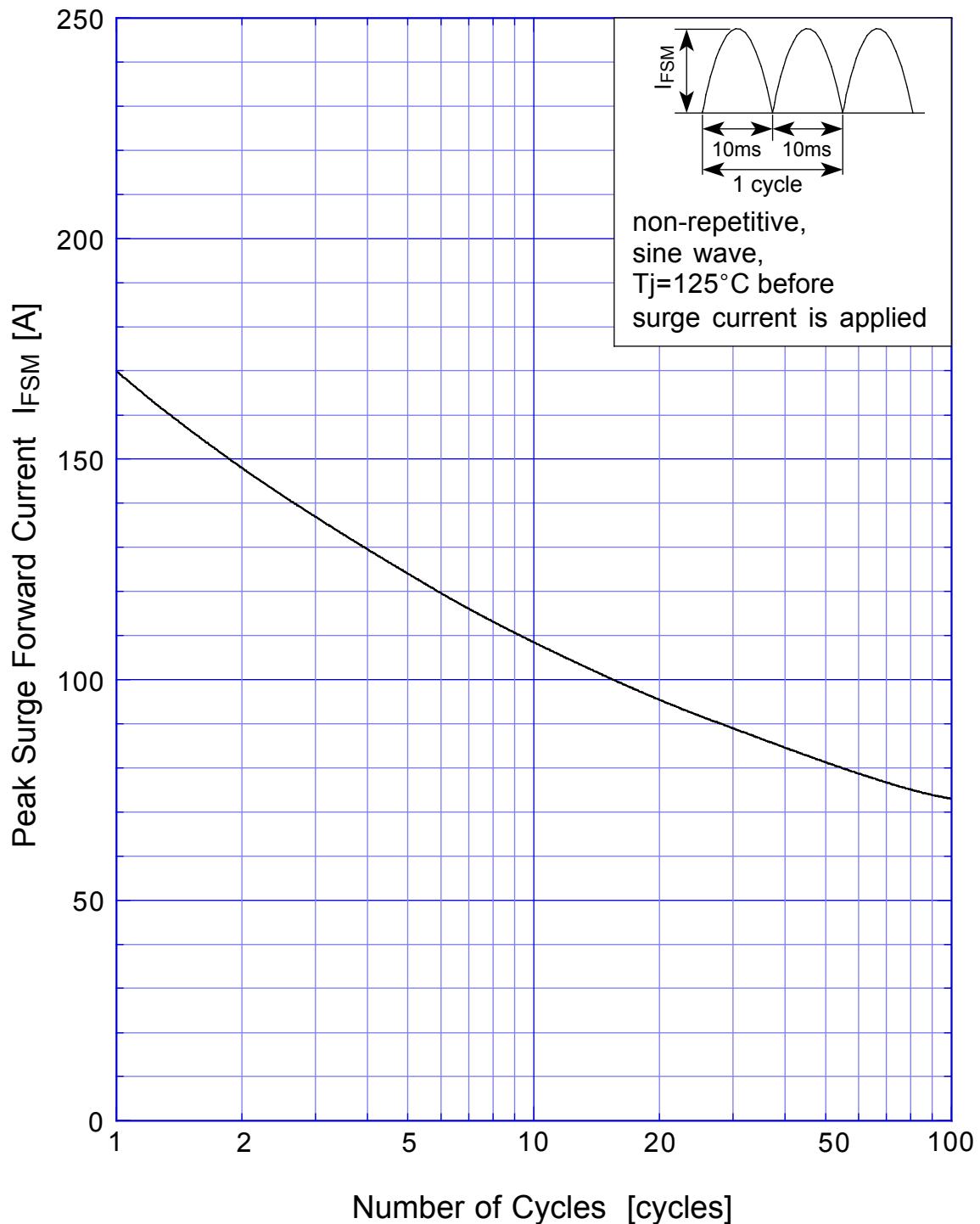


S15SC4M Forward Power Dissipation





S15SC4M Peak Surge Forward Capability



SBD Repetitive Surge Reverse Power Derating Curve



SBD Repetitive Surge Reverse Power Capability

